GREEN

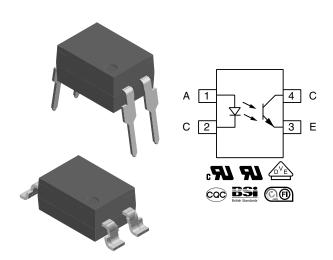
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Vishay Semiconductors

Optocoupler, Phototransistor Output, High Reliability, 5300 V_{RMS}



DESCRIPTION

The 110 °C rated VO617A feature a high current transfer ratio, low coupling capacitance and high isolation voltage. These couplers have a GaAs infrared diode emitter, which is optically coupled to a silicon planar phototransistor detector, and is incorporated in a plastic DIP-4 package.

The coupling devices are designed for signal transmission between two electrically separated circuits.

The couplers are end-stackable with 2.54 mm spacing.

Creepage and clearance distances of > 8.0 mm are achieved with option 6. This version complies with IEC 60950 (DIN VDE 0805) for reinforced insulation up to an operation voltage of 400 V_{RMS} or DC. Specifications subject to change.

FEATURES

- Operating temperature from 55 °C to + 110 °C
- Good CTR linearity depending on forward current
- Isolation test voltage, 5300 V_{RMS}
- High collector emitter voltage, V_{CEO} = 80 V
- Low saturation voltage
- · Fast switching times
- · Low CTR degradation
- Temperature stable
- Low coupling capacitance
- End stackable, 0.100" (2.54 mm) spacing
- High common mode interference immunity
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

- AC adapters
- SMPS
- PLC
- · Factory automation
- · Game consoles

AGENCY APPROVALS

- UL1577, file no. E52744
- cUL tested to CSA 22.2 bulletin 5A
- DIN EN 60747-5-5 (VDE 0884-5), available with option 1
- BSI IEC 60950; IEC 60065
- FIMKO EN 60065, EN 60950-1
- CQC GB8898-2001

ORDERING INFORMATION DIP-4 Option 6 ٧ 0 7 Α Χ Т 6 0 7.62 mm 10.16 mm TAPE PART NUMBER CTR PACKAGE OPTION **AND** Option 7 RFFI **CTR (%) AGENCY CERTIFIED/PACKAGE** 5 mA UL, cUL, BSI, FIMKO 50 to 600 40 to 80 63 to 125 100 to 200 160 to 320 80 to 160 130 to 260 DIP-4 VO617A VO617A-2 VO617A-3 VO617A-4 VO617A-1 DIP-4, 400 mil, option 6 VO617A-3X006 VO617A-4X006 VO617A-2X007T VO617A-3X007T VO617A-4X007T SMD-4, option 7 VDE, UL, cUL, BSI, FIMKO 50 to 600 63 to 125 100 to 200 160 to 320 80 to 160 40 to 80 130 to 260 DIP-4, 400 mil. option 6 VO617A-3X016 VO617A-4X016 VO617A-3X017T SMD-4, option 7 VO617A-1X017T VO617A-2X017T VO617A-4X017T VO617A-7X017T VO617A-8X017T

Note

Additional options may be possible, please contact sales office.



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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
INPUT	·					
Reverse voltage		V _R	6	V		
Forward current		I _F	60	mA		
Forward surge current	t _p ≤ 10 μs	I _{FSM}	2.5	Α		
LED power dissipation	at 25 °C	P _{diss}	70	mW		
OUTPUT	·					
Collector emitter voltage		V _{CEO}	80	V		
Emitter collector voltage		V _{ECO}	7	V		
Collector current		I _C	50	mA		
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I _{CM}	100	mA		
Ouput power dissipation	at 25 °C	P _{diss}	150	mW		
COUPLER	·					
Isolation test voltage (RMS)	t = 1 min	V _{ISO}	5300	V_{RMS}		
Total power dissipation		P _{tot}	200	mW		
Operation temperature		T _{amb}	- 55 to + 110	°C		
Storage temperature range		T _{stg}	- 55 to + 150	°C		
Soldering temperature (1)	2 mm from case, ≤ 10 s	T _{sld}	260	°C		

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
 implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
 maximum ratings for extended periods of the time can adversely affect reliability.
- (1) Refer to reflow profile for soldering conditions for surface mounted devices (SMD), and wave profile for soldering conditions for through hole devices (DIP), please go to "Assembly Instructions" (www.vishav.com/doc?80054).

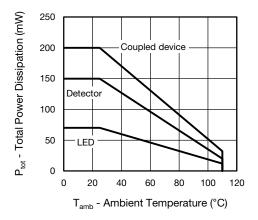


Fig. 1 - Total Power Dissipation vs. Ambient Temperature



ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT							
Forward voltage	$I_F = 60 \text{ mA}$		V_{F}	1	1.35	1.65	V
Reverse current	V _R = 6 V		I _R		0.01	10	μΑ
Junction capacitance	$V_R = 0 V$, $f = 1 MHz$		C _j		13		pF
OUTPUT							
	V _{CE} = 10 V	VO617A-1	- I _{CEO}		2	50	nA
		VO617A-2			2	50	
Collector emitter leakage augrent		VO617A-3			5	100	
Collector emitter leakage current		VO617A-4			5	100	
		VO617A-7			5	100	
		VO617A-8			5	100	
Collector emitter capacitance	$V_{CE} = 5 \text{ V}, f = 1 \text{ MHz}$		C _{CE}		5.2		pF
Collector emitter breakdown voltage	$I_C = 1 \text{ mA}$		BV _{CEO}	80			V
Emitter collector breakdown voltage	I _E = 100 μA		BV _{ECO}	7			V
COUPLER							
Collector emitter saturation voltage	$I_F = 5 \text{ mA}, I_C = 1.0 \text{ mA}$		V _{CEsat}		0.25	0.4	V
Coupling capacitance	f = 1 MHz		C _C		0.4		pF

Note

• Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

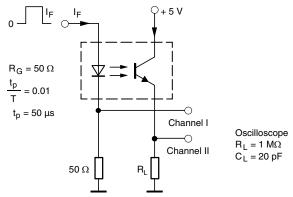
CURRENT TRANSFER RATIO (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
I _C /I _F		VO617A	CTR	50		600	%
		VO617A-1	CTR	40		80	%
	1	VO617A-2	CTR	63		125	%
	$I_F = 5 \text{ mA}, V_{CE} = 5 \text{ V}$	VO617A-3	CTR	100		200	%
		VO617A-4	CTR	160		320	%
		VO617A-7	CTR	80		160	%
		VO617A-8	CTR	130		260	%

SWITCHING CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	CTR BIN	SYMBOL	MIN.	TYP.	MAX.	UNIT
NON-SATURATED							
Rise and fall time	$I_F = 5 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 75 \Omega$		t _r , t _f		2		μs
Turn-on time	$I_E = 5 \text{ mA}, V_{CC} = 5 \text{ V}, R_1 = 75 \Omega$		t _{on}		3		μs
Turn-off time	$I_F = 3 \text{ IIA}, V_{CC} = 3 \text{ V}, H_L = 73 \Omega$		t _{off}		2.3		μs
Cut-off frequency	$I_F = 5$ mA, $V_{CC} = 5$ V, $R_L = 75$ Ω		f _{ctr}		100		kHz
SATURATED							
Turn-on time	I _F = 5 mA		t _{on}		6		μs
Turn-off time	I _F = 5 mA		t _{off}		25		μs
Rise time	I _F = 5 mA		t _r		4.6		μs
Fall time	I _F = 5 mA		t _f		15		μs



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Fig. 2 - Test Circuit, Non-Saturated Operation

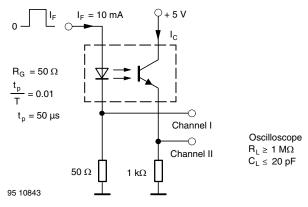


Fig. 3 - Test Circuit, Saturated Operation

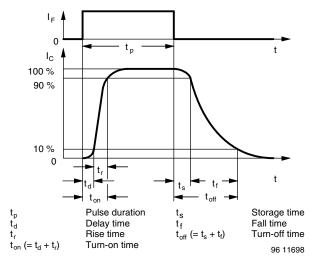


Fig. 4 - Switching Times

SAFETY AND INSULATION R	ATINGS			
PARAMETER	SYMBOL	VALUE	UNIT	
MAXIMUM SAFETY RATINGS				
Output safety power		P _{SO}	265	mW
Input safety current		I _{si}	130	mA
Safety temperature		T _S	150	°C
Comparative tracking index		CTI	175	
INSULATION RATED PARAMETERS				
Maximum withstanding isolation voltage	V _{ISO}	5300	V _{RMS}	
Maximum transient isolation voltage	V _{IOTM}	8000	V _{peak}	
Maximum repetitive peak isolation voltage		V _{IORM}	890	V _{peak}
Insulation resistance	$T_{amb} = 25 ^{\circ}\text{C}, V_{DC} = 500 \text{V}$	R _{IO}	10 ¹²	Ω
Isolation resistance	T _{amb} = 100 °C, V _{DC} = 500 V	R _{IO}	10 ¹¹	Ω
Climatic classification (according to IEC		55/110/21		
Environment (pollution degree in accord	ance to DIN VDE 0109)		2	
Internal and automal areanan	Standard DIP-4		≥ 7	mm
Internal and external creepage 400 mil DIP-4			≥ 8	mm
Classes	Standard DIP-4		≥ 7	mm
Clearance	400 mil DIP-4		≥ 8	mm
Insulation thickness		0.4	mm	

Note

As per DIN EN 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance
with the safety ratings shall be ensured by means of protective circuits.



TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

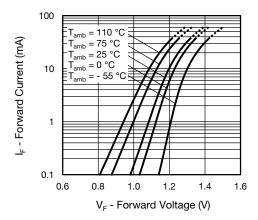


Fig. 5 - Forward Voltage vs. Forward Current

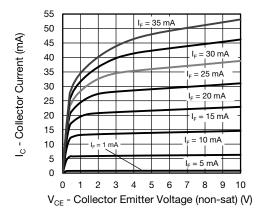


Fig. 6 - Collector Current vs. Collector Emitter Voltage (NS)

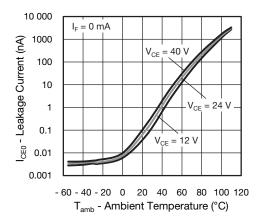


Fig. 7 - Leakage Current vs. Ambient Temperature

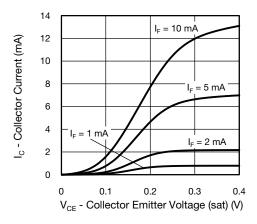


Fig. 8 - Collector Current vs. Collector Emitter Voltage (sat)

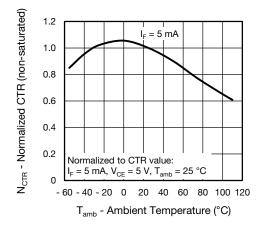


Fig. 9 - Normalized Current Transfer Ratio (non-sat) vs.
Ambient Temperature

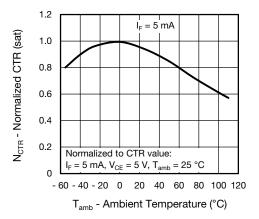


Fig. 10 - Normalized Current Transfer Ratio (sat) vs.
Ambient Temperature

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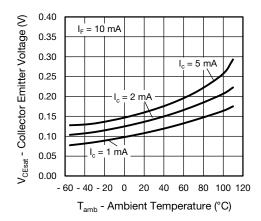


Fig. 11 - Collector Emitter Voltage vs. Ambient Temperature (saturated)

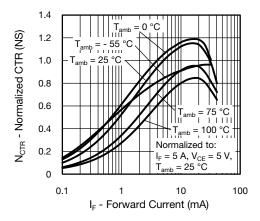


Fig. 12 - Normalized CTR (NS) vs. Forward Current

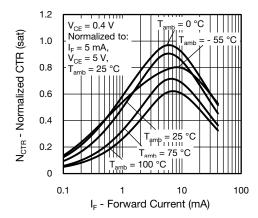


Fig. 13 - Normalized CTR (sat) vs. Forward Current

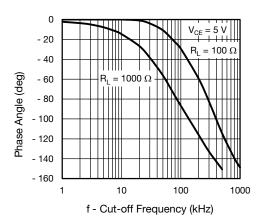


Fig. 14 - F_{CTR} vs. Phase Angle

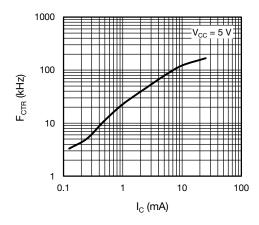


Fig. 15 - F_{CTR} vs. Collector Current

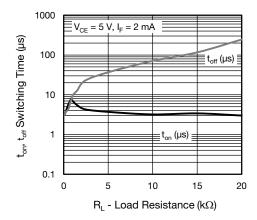
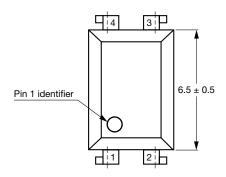


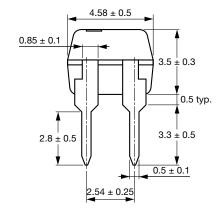
Fig. 16 - Switching Time vs. Load Resistance

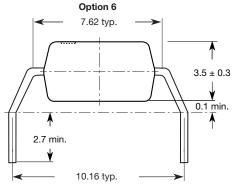
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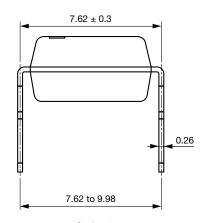


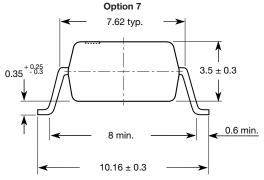
PACKAGE DIMENSIONS in millimeters













PACKAGE MARKING (example of VO617A-3X017T)



Notes

- The VDE logo is only marked on option 1 parts. Option information is not marked on the part.
- Tape and reel suffix (T) is not part of the package marking.

PACKING INFORMATION

DEVICE PER TUBE						
TYPE	UNITS/TUBE	TUBES/BOX	UNITS/BOX			
DIP-4	100	40	4000			

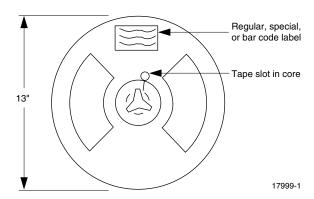


Fig. 17 - Tape and Reel Shipping Medium (1000 units per reel)

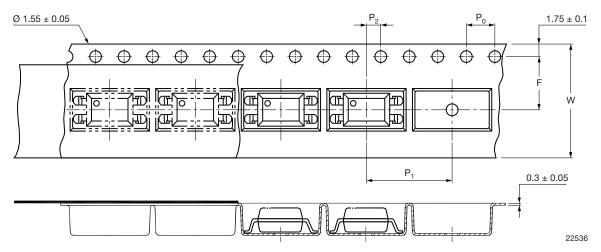


Fig. 18 - Tape and Packing for Option 7



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